

### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	I <sub>D</sub> TA = +25°C
-50V	6Ω @ V <sub>GS</sub> = -4V	-160mA
-507	8Ω @ V <sub>GS</sub> = -2.5V	-120mA

### **Descriptions and Applications**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- DC-DC converters
- Power management functions
- Battery operated systems and solid-state relays

# Features and Benefits

- Low On-Resistance
- ESD Protected Gate
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

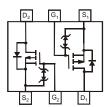
### Mechanical Data

- Package: SOT563
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (Approximate)





TOP VIEW



TOP VIEW Internal Schematic

#### Ordering Information (Note 4)

Part Number	Package	Pac	king
	Fackage	Qty.	Carrier
DMP56D0UV-7	SOT563	3000	Tape & Reel
DMP56D0UV-13	SOT563	10000	Tape & Reel

**SOT563** 

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

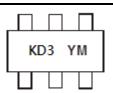
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



### **Marking Information**



KD3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: J = 2022) M = Month (ex: 3 = March)

#### Date Code Key

Year	2013		2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	А		J	К	L	М	Ν	0	Р	R	S	Т
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Units
Drain-Source Voltage		VDSS	-50	V
Gate-Source Voltage	Continuous	V <sub>GSS</sub>	±8	V
Drain Current (Note 5)	Continuous	lD	-160	mA
Pulsed Drain Current (10µs pulse, d	uty cycle = 1%)	ldм	-700	mA

#### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	400	mW
Thermal Resistance, Junction to Ambient (Note 5)	Reja	313	°C/W
Operating and Storage Temperature Range	TJ, T <sub>STG</sub>	-55 to +150	°C

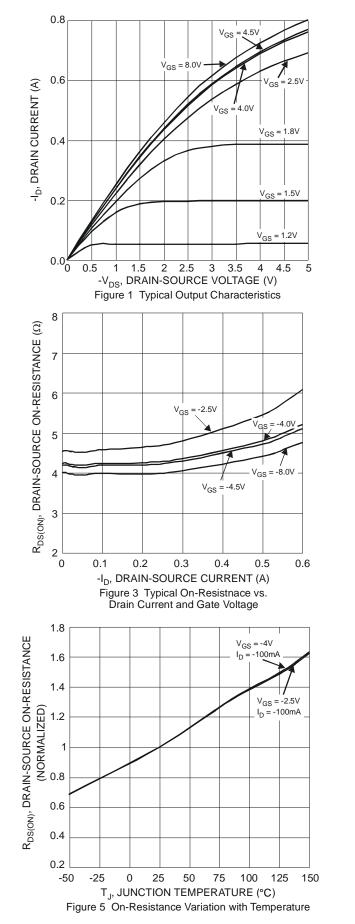
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

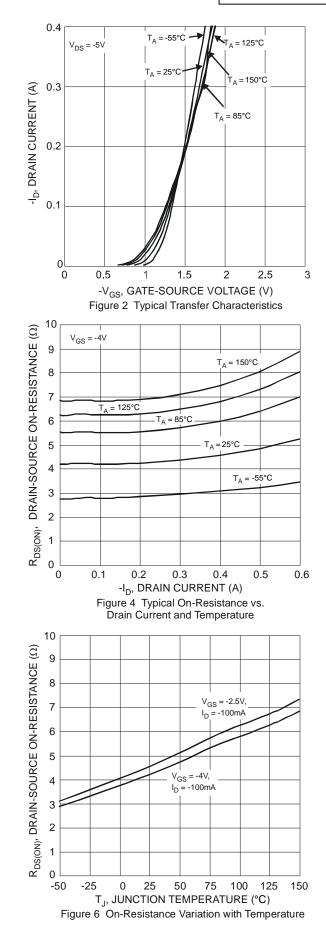
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BVDSS	-50	_	_	V	Vgs = 0V, Id = -250µA
Zero Gate Voltage Drain Current	IDSS	_	—	-10	μA	$V_{DS} = -50V, V_{GS} = 0V$
Gate-Body Leakage	lgss	_	—	±1	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 6)						·
Gate Threshold Voltage	VGS(TH)	-0.5		-1.2	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Proven	_	4.6	6	Ω	V <sub>GS</sub> = -4V, I <sub>D</sub> = -100mA
	R <sub>DS(ON)</sub>		6.0	8	32	$V_{GS} = -2.5V, I_{D} = -80mA$
Forward Transfer Admittance	Yfs	100		_	mS	$V_{DS} = -5V, I_{D} = -100mA$
Diode Forward Voltage	V <sub>SD</sub>		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -100mA$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss		50.54	_	pF	
Output Capacitance	Coss		3.49	_	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.42	_	pF	
Gate Resistance	R <sub>G</sub>		201	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge V <sub>GS</sub> = 4.5V	Qg	_	0.58		nC	
Gate-Source Charge	Qgs	_	0.09	_	nC	V <sub>DS</sub> = -25V, I <sub>D</sub> = -100mA
Gate-Drain Charge	Q <sub>gd</sub>	_	0.14		nC	
Turn-On Delay Time	tD(on)	_	4.46		ns	
Turn-On Rise Time	tr	_	6.63		ns	VDD = -30V, ID = -0.27A, VGEN = -4V,
Turn-Off Delay Time	tD(off)	_	21.9		ns	$R_{GEN} = 6\Omega$
Turn-Off Fall Time	t <sub>f</sub>	_	15.0		ns	

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided. Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.



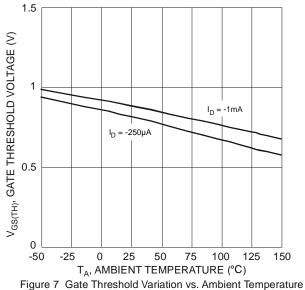


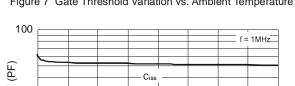


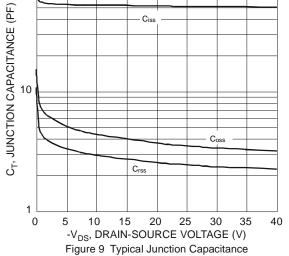
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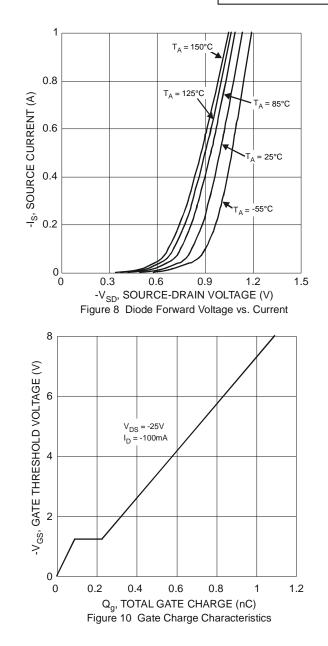


# DMP56D0UV



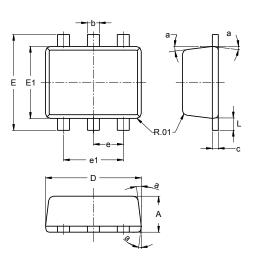








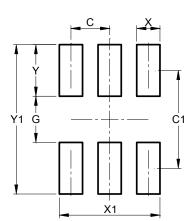
### **Package Outline Dimensions**



SOT563						
Dim	Min	Max	Тур			
Α	0.55	0.60				
b	0.15	0.30	0.20			
С	0.10	0.18	0.11			
D	1.50	1.70	1.60			
Е	1.55	1.70	1.60			
E1	1.10	1.25	1.20			
е			0.50			
e1	0.90	1.10	1.00			
L	0.10	0.30	0.20			
а	8°	9°	7°			
All Dimensions in mm						

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563

**SOT563** 

Dimensions	Value (in mm)
С	0.500
C1	1.270
G	0.600
Х	0.300
X1	1.300
Y	0.670
Y1	1.940

Please see http://www.diodes.com/package-outlines.html for the latest version.



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